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# **ARTICLE**

# A novel quartz-crystal microbalance humidity sensor based on solution-processible indium oxide quantum dots

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Large surface area, like quantum confinement effect also caused by particular nano level size of quantum dots (QDs), brings fantastic possibility for humidity sensing. High concentration of surface adsorption site initiate response increasing. Porosity between QDs stacking up fast water vapor penetration and flowing away. Here, a quartz-crystal microbalance (QCM) humidity sensor was prepared using the indium oxide (In<sub>2</sub>O<sub>3</sub>) QDs, synthesized via solvothermal method. After In<sub>2</sub>O<sub>3</sub> QDs directly spin-coating onto the QCM, an annealing process taken place to remove organic long chains and expose more moisture adsorption sites on the surface of the QDs. The annealed QCM humidity sensor exhibited high sensitivity (56.3 Hz/%RH at 86.3% RH), with a fast response/recovery time (14 s/16 s). Long carbon chains break down and hydrogen-bonded hydroxyl groups chemisorpted to the QDs. Chemical reaction was reduced by these chemisorpted hydrogen-bonded hydroxyl groups. Mass changing was mostly caused by fast multilayer physiorption. So the transducer can effectively and precisely monitor the moisture of person's breathing. In<sub>2</sub>O<sub>3</sub> QDs modified QCM sensors demonstrating its promising humidity sensing applications in daily life.

# Introduction

Humidity sensors have been widely used in the fields of chemistry, electronics, food storage, mining, meteorology, agriculture and medicine, etc.. 1-4 Accurate and real-time monitoring of humidity is also critical for human safety and social activities. Therefore, it is critically required to develop a high-performance, repeatable and low-cost humidity sensor. So far, various of sensing technologies have been developed for humidity sensors, including resistance, optical, magnetic, capacitance acoustic and thermal, etc.. 5-9 Among these, quartz crystal microbalance (QCM) is one of the most promising and key technology due to their merits such as low power consumption, easy operation, low cost, good sensitivity and extremely trace mass detection. By monitoring the shifts of the resonance frequency in real time, the mass change caused by water molecules can be precisely detected using the Sauerbrey equation.<sup>10</sup> Therefore, QCM sensors have been extensively researched as humidity sensors by more and more researchers.

Based on the above advantages, various sensitive materials such as 0-dimensional (0D) QDs, 1-dimensional (1D) nanowires, graphene, reduced graphene oxide (RGO), black phosphorus and many types of polymers have been applied on the surface of QCM humidity sensors. 16-22 Obviously, these nanomaterials provide numerous reactive sites due to their larger specific surface areas, resulting in improved humidity sensing performance. Among them, 0D QDs exhibit wide-range potential applications in the field of humidity sensors due to their low cost, large specific surface areas and easy solution processes capabilities.23-25 For example, Sun et al. prepared well-crystallized black phosphorus QDs from bulk black phosphorus using a kitchen blender, and the sensor using the black phosphorus QDs showed outstanding humidity sensing performance.26 A flexible humidity sensor fabricated using graphene QDs was reported by Hossein et al., and the response of the transducer was quite high with good selectivity and flexibility.<sup>27</sup> Another QCM humidity sensor based on ZnO QDs sensitive film was reported by Sakly et al., and it exhibited high sensitivity, fast response/recovery speed and outstanding longterm stability.<sup>28</sup> Therefore, QDs with high specific surface area is a very promising type of humidity sensitive material.

Based on the discussion above, in the present work, we fabricated a QCM humidity sensor based on In<sub>2</sub>O<sub>3</sub> QDs. The In2O3 QDs were spin-coated on the top of the electrodes of QCMs in the form of thin films, then the devices were annealed at 300°C in air for one hour to remove long chain carbons on the surface of the QDs. The humidity sensing performance of the QCM sensor was characterized at room temperature from 11.3% to 84.3% relative humidity (RH). It showed remarkable sensing characteristics, including high sensitivity (56.4 Hz/%RH), fast response/recovery (14 s/ 16 s) time, good stability and

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excellent selectivity for moisture. We believe this work provides a simple and easy way to fabricate a novel QCM humidity sensors based on  $In_2O_3$  QDs.

#### **Experimental section**

#### In<sub>2</sub>O<sub>3</sub> QDs synthesis and device preparation

The  $In_2O_3$  QDs were synthesized via a modified method employing oleic acid (OA) and oleylamine (OLA) as the surfactants.<sup>29</sup> Briefly, 0.146g indium acetate, 12.5 mL OLA and 5 mL OA were mixed inside a three-necked flask. The mixtures were heated under vacuum at 90°C until indium acetate was completely dissolved. Then, the solution was kept under a nitrogen atmosphere and heated to 240°C for 30 min. Finally,  $In_2O_3$  QDs were washed with ethanol and toluene, and eventually dispersed in toluene with a concentration of 20 mg/mL.

The QCM devices with a resonant frequency of 8 MHz were purchased from Wuhan Hi-Trusty Electronics Co., Ltd., China. It was consisted of an AT-cut quartz crystal (with size of 8 mm in diameter) and silver electrodes (with size of 5 mm in diameter) on both sides (Figure 1a). Before preparing  $\mbox{In}_2\mbox{O}_3$  QDs film, all the QCM devices were washed with ethanol and deionized water, and then dried with nitrogen. The film coated QCM sensors were achieved by spin-coating method and postannealing process (Figure 1b). Specifically, 20 μL In<sub>2</sub>O<sub>3</sub> QDs solution was spin-coated onto the QCM device at 1200 rpm for 45 s. To remove organic long chains on the surface of In<sub>2</sub>O<sub>3</sub> QDs, an annealing process in air at 300  $^{\circ}\text{C}$  for 1 h was carried out. This fabrication procedure of the QCM humidity sensor was shown in Figure 1b. In order to study the influences of the depositing amount of In<sub>2</sub>O<sub>3</sub> QDs on sensing performance, three sensors with different deposition repeated cycles were prepared (2, 4, 6 times), which were marked as QCM-1, QCM-2 and QCM-3, respectively. The resonant frequency and the frequency after coating with the film were measured, and the mass of the In<sub>2</sub>O<sub>3</sub> QDs deposited on the electrode of QCMs were calculated using the Sauerbrey equation. 10 All the detailed parameters of the samples are listed in Table 1.

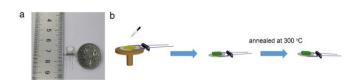


Figure 1. (a) The photograph of QCM device. (b) Fabrication procedure of the QCM humidity sensor based on  $\ln_2 O_3$  QDs.

Table 1. Preparation parameters of the fabricated samples

Samples	Fundamental	Frequency	Load mass (ng)
	frequency	shifts (Hz)	
QCM-1	7999890	-7266	9852
QCM-2	7999867	-14955	19794
QCM-3	7999799	-21004	28479

#### Sensing measurement

The schematic diagram of the experiment apparatus for the QCM humidity measurement is given in Figure 2. It was composed of QCM humidity sensor, humidity sources, computer and QCM-I (Microvacuum Ltd., Hungary). Saturated solutions of LiCl, MgCl<sub>2</sub>, K<sub>2</sub>CO<sub>3</sub>, NaBr, NaCl and KCl were prepared which could provide different humidity environments in a conical flask with RH levels of 11.3%, 32.8%, 43.2%, 57.6%, 75.3% and 84.3% RH, respectively. The response time was defined as the time for the frequency change approaching 90% of the total frequency change, and the recovery time was defined as the time when the get back to 10% of the total frequency change. All the tests were performed at ambient temperature of 25°C.

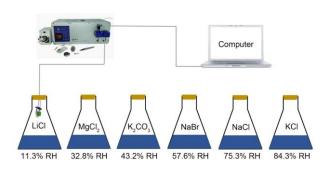


Figure 2. Schematic diagram of QCM humidity test system.

#### Characterization

X-ray diffraction (XRD) analysis of the QD films was performed using a diffractometer (MAXima XXRD-7000, Shimadzu, Japan) with Cu K $\alpha$  radiation. The optical absorption spectra of the QDs were measured using a PerkinElmer Lambda 950 UV/vis/NIR spectrometer. Surface morphologies of the QDs samples were characterized using a scanning electron microscope (SEM, Zeiss Supra 55 microscope). High-resolution transmission electron microscopy (HR-TEM) was carried out using a JEOL-2100 microscope. The Fourier transform infrared (FTIR) spectroscopy were measurements by VERTEX 70 (Bruker, Germany).

#### Results and discussion

Figure 3a shows the crystallization characteristics of the  $In_2O_3$  QDs. The XRD patterns of the synthesized  $In_2O_3$  QDs are in good agreement with the standard diffraction results listed in the JCPDS card (NO. 65-3170), indicating the synthesized QDs have good crystallinity and no other impurities appear. Figure 3b shows a TEM image of  $In_2O_3$  QDs. It was observed that the  $In_2O_3$  QDs were uniformly dispersed and had an average diameter of 3.9 nm. This indicates that the diameter of the as-synthesized  $In_2O_3$  QDs is less than twice of the Bohr exciton radius of the  $In_2O_3$  QDs is less than twice of the as-synthesized  $In_2O_3$  has quantum size.  $In_2O_3$  The transparent lattice fringes of atomic spacing associated with the (222) plane of the  $In_2O_3$  phase can also be observed as shown in the inset of Figure 3b. This demonstrates that the  $In_2O_3$  QDs have good crystallinity. Figure 3c shows the absorption spectrum of as-synthesized  $In_2O_3$  QDs

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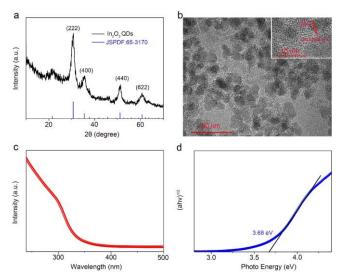


Figure 3. (a) XRD pattern of as-synthesized  $In_2O_3$  QDs. (b) TEM image of the  $In_2O_3$  QDs, the insets is HRTEM image of the  $In_2O_3$  QDs (c) UV–vis absorption spectrum of the assynthesized  $In_2O_3$  QDs (d) The bandgap of the as-synthesized  $In_2O_3$  QDs.

in hexane. The band gap of as-synthesized  $In_2O_3$  QDs calculated by the Tauc model is about 3.68 eV (shown in the Figure 3d), which is larger than that of bulk  $In_2O_3$  (2.93±0.15 eV). This result indicates that the as-synthesized  $In_2O_3$  QDs have quantum confinement effect. As shown in Figure S1, the nitrogen adsorption and desorption isotherm cures of  $In2O_3$  QDs are investigated. The surface area of  $In2O_3$  QDs is calculated to be about 63.9 m2/g through the Brunauer Emmett Teller theory. As is known, high specific surface area can provide more active sites to promote the adsorption of water molecules, thus improving the humidity sensing.

The as-synthesized  $In_2O_3$  QDs were capped with organic long-chain (OA and OLA), and these hydrophobic organic long-chains can inhibit water molecules to be adsorbed onto the surface of  $In_2O_3$  QDs. $^{32,33}$  To remove the organic long chains, the  $In_2O_3$  QDs films should be annealed at 300°C in air. In order to study the effect of annealing process on the QDs, we use FTIR to analyse the  $In_2O_3$  QDs films before and after annealing, and the results are shown in Figure 4. Compared to the as-prepared  $In_2O_3$  QDs film (red line), the characteristic absorption peaks of the aliphatic C-H stretching bands (2850-2920 cm-1) are

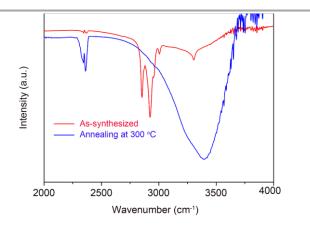


Figure 4. FTIR spectra of the untreated and annealed  $In_2O_3$  QDs film.

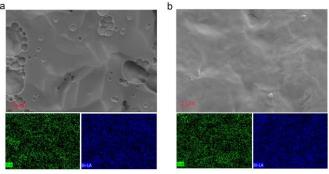


Figure 5. (a) The as-prepared  $In_2O_3$  QDs film. (b) The  $In_2O_3$  QDs film after annealed at 200% for 1b.

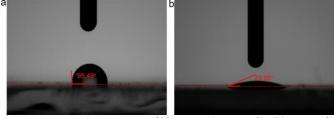


Figure 6. Contact angle measurement of (a) as-papered  $In_2O_3$  QDs film, (b)  $In_2O_3$  QDs film after annealing process.

disappeared after annealing process (blue line), indicating that most of the surface-capped OA and OLA ligands around the  $\rm In_2O_3$  QDs have been removed. As expected, after annealing process, a very strong characteristic peak at around 3445 cm $^{-1}$  appeared (blue line), which is attributed to the hydrogenbonded hydroxyl groups adsorbed on the  $\rm In_2O_3$  QDs. Results, indicate that the  $\rm In_2O_3$  QDs film has an outstanding hydrophilicity after annealing.

The SEM morphologies of the  $In_2O_3$  QDs films before and after annealing were compared. Figure 5a is the SEM image of the as-deposited  $In_2O_3$  QDs film with holes, which may be caused by the evaporation of solvent during the film formation process. After the film annealed at  $300^{\circ}\text{C}$  for 1h, the  $In_2O_3$  QDs film becomes smoother but with some tiny cracks, which are generated owing to the densification with stress relaxation and the removal of organic long-chain ligands during the annealing process. This porous film is beneficial for the adsorption and diffusion of water molecules. The corresponding element mapping obtained from energy dispersive X-ray spectroscopy was shown in Figure 5. The elements of In and O were uniformly dispersed, which indicates that the QDs were uniformly deposited on the top of QCM electrode.

Figure 6 shows The wettability behaviours of  $In_2O_3$  QDs film before and after annealing. The contact angle of the asdeposited QDs film is 95.49° (Figure 6a). This is due to the hydrophobicity of the surface-capped organic long chains. After annealing process, the contact angle of  $In_2O_3$  QDs sensing film is as low as 23.00° (Figure 6b). This value verifies the excellent hydrophilicity of the  $In_2O_3$  QDs sensing film. These results are consistent with FTIR spectrum. Also, the results of FTIR and contact angle suggest that the prepared QCM humidity sensor based on  $In_2O_3$  QDs will have good humidity sensitivity.

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The humidity sensitivity characteristic of the  $In_2O_3$  QDs-based QCM sensor is quantified by changing the RH level in different saturated solution conical flask and measuring the

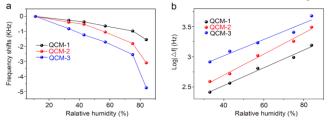


Figure 7. (a) The relationships between the frequency shifts of all the sensors. (b) the linear fitting curves of the Log  $|\triangle f|$  versus humidity for all the sensors.

with test RH between 11.3% and 84.3%. As seen in the figure, the resonant frequency of all the sensors is decreased with the RH increasing. The frequency shifts are 1550 Hz, 3100 Hz and 4750 Hz for three QCM samples, respectively (with RH levels are changed from 11.3% to 84.3%). These indicate that the frequency shifts of the QCM humidity sensor based on  $\rm In_2O_3$  QDs is related to the deposited amount of  $\rm In_2O_3$  QDs. The QCM-3 sensor has the highest frequency offset (sensitivity). This indicates that greater amount of  $\rm In_2O_3$  QDs can adsorb more water molecules. As shown in Figure 7b, the frequency response of the three sensors exhibit very good log relationship with humidity, which is consistent with the results of other reported humidity sensors.  $^{34,35}$  The regression coefficients R² of QCM-1, QCM-2 and QCM-3 sensors are 0.98411, 0.9899 and 0.97367, respectively.

QCM-3 sample with optimal humidity sensitivity were chosen for further testing. Figure 8a shows the dynamic frequency changes of the QCM-3 transducer. The sensor was tested twice with the RH levels changed from 11.3% RH to 32.8%RH, 43.2%RH, 57.6%RH, 75.3%RH and 84.3%RH. The frequency responses are not change significantly under the same humidity conditions, indicating that the humidity sensor has excellent RH measurement repeatability. The response / recovery time is another crucial parameter for evaluating humidity sensing performance. The response and recovery characteristic curves between RH levels of 11.3% and 75.3% are shown in Figure 8b. As can be seen, the response and recovery time of QCM-3 transducer are 14 s and 16 s, respectively, which indicates the sensor based on  $\ln_2 O_3$  QDs films have fast

changes of resonance frequency. Figure 7a shows the relationship between frequency shifts vs. RH for three sensors

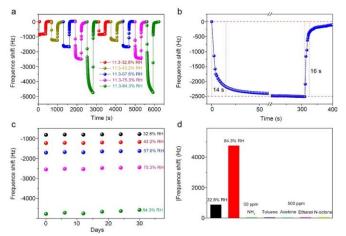


Figure 8. (a) The dynamic frequency shifts of the QCM-3 transducer. (b) The response and recovery curves between 11.3% and 75.3% conditions. (c) The long-term stability of the sensor. (d) The selectivity of QCM-3 at room temperature.

adsorption and desorption characteristics for water molecules. The long-term stability of the humidity sensor is very important for its practical application. Figure 8c shows the long-term stability of QCM humidity sensor based on  $In_2O_3$  QDs. The frequency shifts of the sensor do not show apparent changes under different humidity conditions within 30 days. This result indicates that the sensor has a good long-term stability. The selectivity testing results of the QCM device are shown in Figure 8d. It demonstrated that the frequency shifts of the QCM sensor based on In<sub>2</sub>O<sub>3</sub> QDs toward water molecules are much higher than those towards the commonly used target gases, including NH<sub>3</sub>, ethanol, acetone, toluene, n-octane. Hence, the sensor has an excellent selectivity toward water molecules at room temperature. Finally, we summarized the reported humidity sensing performance of the QCM sensor in recent literature (Table 2). The results indicated that our sensor exhibits outstanding sensitivity and fast response and recovery times.

In order to demonstrate the application of QCM sensors based on  $In_2O_3$  QDs for humidity detection, we further measure the human mouth breath via these sensors. As it is shown in Figure 9, breath from the mouth causes a sharp frequency decrease due to increase of the RH level suddenly. Hence, the

Table 2. The reported humidity sensing performance of the QCM sensor

Materials	RH Range (%)	Sensitivity	Response/Recovery time	Ref.
ZnO/GO	11-97	41.10Hz/%RH	9/5 s (@63.2%)	11
GQDs-chitosan	11-95	39.2 Hz/%RH	36/ 3 s (@95%)	36
SnO <sub>2</sub> -SiO <sub>2</sub>	11-96	9.4 Hz/%RH	14/ 16 s (@90%)	37
ZnO colloid spheres	11-95	77 Hz/%RH	167.7/ 8 s(@95%)	38
GO/PEI	11-97	27.3 Hz/%RH	53/18 s (@90%)	39
In <sub>2</sub> O <sub>3</sub> QDs	11.3-84.3	56.3 Hz/%RH	14/16 s (@74.3%)	This work

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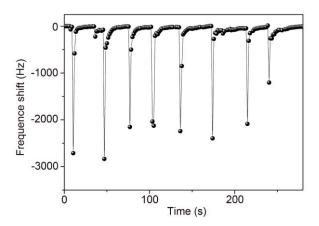


Figure 9. The frequency response of human mouth breath.

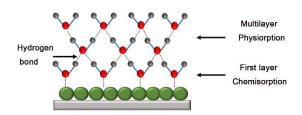


Figure 10. Schematic diagram of the humidity sensing mechanism of the  $\mbox{In}_2\mbox{O}_3$  QDs QCM humidity sensor

QCM sensor can detect the human respiration. These results show that the  $In_2O_3$  QDs QCM sensor possess outstanding sensitivity to humidity, which can be used for human survival.

The humidity sensing mechanism of the In<sub>2</sub>O<sub>3</sub> QDs QCM humidity sensor depends on adsorption/desorption of water molecules (Figure 10). Here, In<sub>2</sub>O<sub>3</sub> QDs have abundant surface oxygen vacancies and a large specific surface area, which play an important role in improving sensing performance. First, the chemical absorption of water molecules forms OH- on the surface of In<sub>2</sub>O<sub>3</sub> QDs. Second, more water molecules will be physically adsorbed on the hydroxyl groups through the van der Waals force. As the ambient humidity increases, more water molecules will be adsorbed on the surface of the sensitive film, and the resonant frequency will decrease due to the mass gain of the QCM surface. In contrast, as the environmental RH decreases, water molecules on the surface of the sensitive film are desorbed and released into the environment. Then, the mass loading effect is decreased and the resonant frequency is increased. More water molecules will need more time for relative balance absorb/desorb state, so the response/recovery time of the sensor will be longer at high humidity.

### Conclusion

In summary, QCM humidity sensors were fabricated by employing  $In_2O_3$  QDs that were synthesized using solventhermal method. The  $In_2O_3$  QDs films were prepared by spin-coating due the well solution processing properties, then the films were annealed at  $300^{\circ}$ C in order to increase its surface

hydrophilicity. This sensor has outstanding sensitivity and short response/recovery time for humidity detection. Meantime, the sensor has been used to monitor the breath of the mouth, showing its potential for fast humidity detection in practical application. Furthermore, we discussed the humidity sensing mechanisms of this sensor. This study provided a new QDs humidity sensing material and expanded the application of QDs in QCM humidity sensors.

#### **Conflicts of interest**

There are no conflicts to declare.

# **Acknowledgements**

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#### References

- S. Wei, D. D. Han, L. Guo, Y. Y. He, H. Ding, Y. L. Zhang and F. S. Xiao, J. Colloid Interfaces Sci., 2014, 431, 17–23.
- E. Pál, V. Hornok, R. Kun, A. Oszkó, T. Seemann, I. Dékány and M. Busse, J. Colloid Interfaces Sci., 2012, 378, 100–109.
- 3 P. Tian, X.Y Gao, G. Wen, L. S. Zhong, Z. Wang and Z. Guo, J. Colloid Interfaces Sci., 2018, 532, 517–526.
- 4 H. Kaden, F. Königer, M. Strømme, G.A. Niklasson and K. Emmerich, *J. Colloid Interfaces Sci.*, 2013, **411**, 16–26.
- 5 S. Kano, K. Kim and M. Fujii, ACS Sens., 2017, 2, 828-833.
- 6 B. B. Du, D. X. Yang, X. Y. She, Y. Yuan, D. Mao, Y. J. Jiang and F. F. Lu, Sens. Actuators B: Chem., 2017, 251, 180–184.
- 7 X. H. Le, X. Y. Wang, J. T. Pang, Y. J. Liu, B. Fang, Z. Xu, C. Gao, Y. Xu and J. Xie, Sens. Actuators B: Chem., 2018, 255, 2454–2461.
- S. Choi, H. Y. Yu, J. Jang, M. Kim, S. Kim, H. S. Jeong and D. Kim, Small, 2018, 14, 1703934.
- 9 B. Chethan, Y. T. Ravikiran, S. C. Vijayakumari, H. G. Rajprakash and S. Thomas, *Sens. Actuators B: Chem.*, 2018, **280**, 466–474.
- 10 Y. Dong and G. Feng, Sens. Actuators B: Chem., 1995, **24**, 62–
- 11 Z. Yuan, H. L. Tai, X. H. Bao, C. H. Liu, Z. B. Ye and Y. D. Jiang, *Mater. Lett.*, 2016, **174**, 28–31.
- 12 J. b. Lin, N. B. Gao, J. M. Liu, Z. X Hu, H. Fang, X. H. Tan, H. Y. Li, H. Jiang, H. Liu, T. L. Shi and G. L. Liao, J. Mater. Chem. A, 2019, 7, 9068.
- 13 X. L. Cha, F. F. Yu, Y. Fan, J. F. Chen, L. Y. Wang, Q. Xiang, Z. M. Duan and J. Q. Xu, Sens. Actuators B: Chem., 2018, 263, 436–444.
- 14 E. S. Muckley, L. Collins, A. V. Ievlev, X. Y. Ye, K. Kisslinger, B. G. Sumpter, N. V. Lavrik, C. Y Nam and I. N. Ivanov, ACS Appl. Mater. Interfaces., 2018, 10, 31745-31754.

ARTICLE Journal Name

- N. B. Gao, H. Y Li, W. H. Zhang, Y. Z. Zhang, Y. Zeng, Z. X. Hu, J. Y. Liu, J. J. Jiang, L. Miao, F. Yi, and H. Liu, Sens. Actuators B: Chem., 2019, 293, 129–135.
- 16 M. A. Mahjoub, G. Monier, C.R. Goumet, F. Reveret, M. Echabaane, D. Chaudanson, M. Petit, L. Bideux, B. Gruzza, J. Phys. Chem. C, 2016, 120, 11652-11662.
- 17 Z. Q. Wei, Z. K. Zhou, Q. Y. Li, J. C. Xue, A. D. Falco, Z. J. Yang, J. H. Zhou and X. H. Wang, Small, 2017, 13, 1700109.
- 18 C. Melios, A. Centeno, A. Zurutuza, V. Panchal, C. E. Giusca, S. Spencer, S. P. Silva and O. Kazakova, *Carbon*, 2016, **103**, 273-280.
- 19 L. T. Duy, T. Q. Trung, V. Q. Dang, B. Hwang, S. Siddiqui, I. Y. Son, S. K. Yoon, D. J. Chung and N. E. Lee, *Adv. Funct. Mater.*, 2016, 26, 4329–4338.
- 20 P. Yasaei, A. Behranginia, T. Foroozan, M. Asadi, K. Kim, F.K. Araghi and A.S. Khojin, *ACS Nano*, 2015, **9**, 9898–9905.
- 21 M. B. Erande, M. S. Pawar and D. J. Late, ACS Appl. Mater. Interfaces, 2016, 8, 11548-11556.
- 22 S. H. Wu, G. H. Wang, Z. Xue, F. Ge, G. B. Zhang, H. B. Lu and L. Z. Qiu, ACS Appl. Mater. Interfaces, 2017, 9, 14974-14982.
- 23 T. Alizadeh and M. Shokri, *Sens. Actuators B: Chem.*, 2016, **222**, 728–734.
- 24 Z. Lu, Y. Q. Gong, X. J. Li and Y. Zhang, *Appl. Surf. Sci.*, 2017, **399**, 330–336.
- 25 S. Yadav, P. Chaudhary, K. N. Uttam, A. Varma, M. Vashistha and B. C. Yadav, *Nanotechnology*, 2019, **30**, 295501.
- 26 C. Y. Zhu, F. Xu, L. Zhang, M. L. Li, J. Chen, S. H. Xu, G. G. Huang, W. H. Chen and L. T. Sun, *Chem. Eur. J.*, 2016, 22, 7357–7362.

- 27 Z. S. Hosseini, A. Iraji zad, M. A. Ghiass, S. Fardindoost and S. Hatamie, *J. Mater. Chem. C*,2017, **5**, 8966.
- 28 N. Sakly, A. H. Said, and H. B. Ouada, *Mat. Sci. Semicond. Process.*, 2014, **27**, 130–139.
- 29 E. Selishcheva, J. Parisi and J. Kolny-Olesiak, J. Nanopart. Res., 2012, 14, 711.
- 30 Y. Yu, X. Guan, X. Li, W. Li, L. Jiang and D. Chen, *J. Alloys Compd.*, 2016, **672**, 265–270.
- 31 C. Liang, G. Meng, Y. Lei, F. Phillipp and L. Zhang, *Adv. Mater.*, 2010, **13**, 1330–1333.
- 32 E. Selishcheva, J. Parisi and J. Kolny-Olesiak, J. Nanopart. Res., 2012, 14, 711.
- 33 X. Xu, J. Zhuang and X. Wang, *J. Am. Chem. Soc.*, 2008, **130**, 12527–12535.
- 34 X. Zhou, J. Zhang, T. Jiang, X. Wang and Z. Zhu, *Sens. Actuators A*, 2007, **135**, 209–214.
- 35 X. Wang, B. Ding, J. Yu, M. Wang and F. Pan, *Nanotechnology*, 2010, **21**, 055502.
- 36 P. J. Qi, T. Zhang, J. R. Shao, B. Yang, T. Fei and R. Wang, Sens. *Actuators B: Chem.*, 2019, **287**, 93–101.
- 37 Y. Zhu, J. C Chen, H. M. Li, Y. H. Zhu, and J. Q. Xu, Sens. *Actuators B: Chem.*, 2014, **193**, 320–325.
- 38 J. Xie, H. Wang, Y. H. Lin, Y. Zhou and Y. P. Wu, *Sens. Actuators B: Chem.*, 2013, **177**, 1083–1088.
- 39 Z. Yuan, H. Tai, Z. Ye, C. Liu, G. Xie, X. Du and Y. D. Jiang, *Sens. Actuators B: Chem.*, 2016, **234**, 145-154.